

# Supplementary materials for “Quantum anomalous semimetals”

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**One-dimensional time-dependent model** We present an exact solution of a two-level problem to demonstrate the non-Abelian topological properties of 1D massless Wilson fermions. For simplicity, we consider a two-level system,

$$H_{1D}(t) = \frac{\hbar\omega_0}{2} \sin \omega t \sigma_x + \hbar\omega_0 \sin^2 \frac{\omega t}{2} \sigma_y. \quad (1)$$

The Hamiltonian is periodic with a time  $T$ ,  $H_{1D}(t+T) = H_{1D}(t)$ . The instantaneous energy eigenvalues are  $E_\chi = \chi \hbar\omega_0 \sin \frac{\omega t}{2}$  with  $\chi = \pm 1$ . The two bands cross at time  $\omega t = 0$  or  $\omega T = 2\pi$ . The model possesses the glide mirror symmetry,  $\mathcal{G}(\omega t) = \begin{pmatrix} 0 & e^{-i\omega t} \\ 1 & 0 \end{pmatrix}$  such that  $\mathcal{G}(\omega t)H_{1D}(t)\mathcal{G}^{-1}(\omega t) = H_{1D}(t)$ . The symmetry operator has the relation  $\mathcal{G}^2(\omega t) = e^{-i\omega t}$ , and its eigenvalues are  $\chi e^{-i\omega t/2}$ . The two eigen states of  $G(\omega t)$  are  $\phi_\chi(t) = \frac{1}{\sqrt{2}} \begin{pmatrix} \chi e^{-i\omega t/2} \\ 1 \end{pmatrix}$ , which are also the energy eigenstates of  $H(t)$ . Using the instantaneous states as the basis, we can write the time-dependent state as

$$\Psi(t) = \sum_\chi c_\chi(t) \exp[-i \int_0^t E_\chi(t') dt' / \hbar] \phi_\chi(t). \quad (2)$$

Substituting the state into the time-dependent Schrodinger equation, one obtains

$$\partial_t c_\chi = i \sum_{\chi'} \frac{\omega}{4} \chi \chi' \exp[i(\chi - \chi') \frac{\alpha}{2} \sin^2 \frac{\omega t}{4}] c_{\chi'} \quad (3)$$

with  $\alpha = 8\omega_0/\omega$ . Here we have used  $\phi_\chi^\dagger(t) i \partial_t \phi_{\chi'}(t) = \frac{\omega}{4} \chi \chi'$  and the dynamic phase  $\int_0^t dt' \chi \omega_0 \sin \frac{\omega t'}{2} = \chi \frac{4\omega_0}{\omega} \sin^2 \frac{\omega t}{4}$ . Transforming into the form of integral equation,

$$c_\chi(t) = e^{i \frac{\omega t}{4}} \left[ c_\chi(0) - i \frac{\omega}{4} \int_0^t dt' \exp[i\alpha \sin^2 \frac{\omega t'}{4}] c_{-\chi}(t') \right]. \quad (4)$$

For a large value of  $\alpha$ , i.e., the system varies very slowly compared to the energy scale  $\hbar\omega_0$ , and the phase factor oscillates rapidly with time in the integral; thus, the integral part tends to approach zero as  $\alpha \rightarrow +\infty$ . At  $t = T$ , we may utilize the integral

$$\int_0^{\pi/2} dx \exp[i\alpha \sin^2 x] = \frac{\pi}{2} e^{i \frac{\alpha}{2}} J_0\left(\frac{\alpha}{2}\right) \quad (5)$$

where the zero-order Bessel function  $J_0(\frac{\alpha}{2}) \rightarrow \frac{2}{\sqrt{\alpha\pi}} \cos[\frac{\alpha}{2} - \frac{\pi}{4}]$  for a large  $\alpha$ . Thus in the adiabatic condition,  $c_\chi(t) \rightarrow e^{i \frac{\omega t}{4}} c_\chi(t=0)$ . Assume the initial state  $\Psi(t=0) = \sum_\chi c_\chi(t=0) \phi_\chi(t=0)$ . Note that  $\phi_\chi(t+T) = \phi_{-\chi}(t)$ . At  $t = T$ , one obtains

$$\Psi(T) = e^{i \frac{\pi}{2}} \sum_\chi e^{-i \chi \frac{\alpha}{2}} \phi_{-\chi}(0) \phi_\chi^\dagger(0) \Psi(0) = -i \sigma_z e^{-i \frac{\alpha}{2} \sigma_x} \Psi(0). \quad (6)$$

At  $t = 2T$ ,  $\Psi(2T) = e^{i\pi}\Psi(0)$ . The state evolves back to the initial state and gains a  $\pi$  Berry phase after two periods of time.

Furthermore, with the help of numerical calculation, the consequence can be extended to a general case in one dimension.

**Solutions of the domain-wall bound state** The method used in this section can be found in Refs. [1, 2]. We start with the 1D modified Dirac equation,

$$(-i\hbar v\partial_x\sigma_1 + b(x)\partial_x^2\sigma_3)\psi(x) = E\psi(x) \quad (7)$$

where  $b = b_0\text{sgn}(x)$ , the sign of  $b$  changes at  $x = 0$ . To find the solution of the zero-energy bound state, we take  $E = 0$  and multiply  $\sigma_1$  from the left-hand side, it follows that the solution has the form  $\psi(x) = \chi_y\phi(x)$  where  $\chi_y$  is the eigenspinor of  $\sigma_y$  with the eigenvalue  $\eta$ :  $\sigma_2\chi_y = \eta\chi_y$ . Then, the equation is reduced to

$$(\hbar v + \eta b(x)\partial_x)\partial_x\phi(x) = 0. \quad (8)$$

The general solution is  $\partial_x\phi(x) = c\exp[-\int \frac{\hbar v}{\eta b(x)}dx]$  and  $\eta$  is determined by the boundary condition  $\phi \rightarrow 0$  when  $x \rightarrow \pm\infty$ . Thus  $\phi(x) = \chi_y\sqrt{|\frac{\hbar v}{b_0}|}\exp(-|\hbar v x/b_0|)$  with  $\eta = \text{sgn}(b_0)$ .

For a 2D domain wall, we take the periodic boundary condition along the  $y$  direction, and the momentum  $p_y = \hbar k_y$  is a good quantum number. The equation reads

$$[\hbar v(-i\partial_x\sigma_1 + k_y\sigma_2) - b(x)(-\partial_x^2 + k_y^2)\sigma_3]\psi(x, y) = E\psi(x, y). \quad (9)$$

Except for the solutions for the bulk states there always exists the bound state solution near the the domain wall

$$\psi_{2D}(x, y) = \frac{1}{\sqrt{2\pi}}\chi_y\sqrt{\lambda_2(k_y)}\exp(-\lambda_2(k_y)|x| + ik_y y) \quad (10)$$

with  $\lambda_2(k_y) = \frac{\hbar v}{2|b_0|} + \sqrt{\left(\frac{\hbar v}{2b_0}\right)^2 + k_y^2}$ , and the energy dispersion is  $E = \text{sgn}(b_0)v\hbar k_y$ . The effective velocity  $v_{eff} = \partial E/\partial \hbar k_y = \text{sgn}(b_0)v$ , in which the sign of  $b$  determines the flowing direction of particles in the chiral bound states.

For a 3D domain wall, we take the periodic boundary condition along the  $y$  and  $z$  direction. The Hamiltonian is reduced to

$$H_{3D}(x, k_y, k_z) = \hbar v(-i\partial_x\alpha_1 + k_y\alpha_2 + k_z\alpha_3) - b(x)(-\partial_x^2 + k_y^2 + k_z^2)\beta. \quad (11)$$

To solve the equation, we rewrite  $H_{3D}(x, k_y, k_z) = H_{1D}(x, k_y, k_z) + \hbar v(k_y\alpha_2 + k_z\alpha_3)$ . Two solutions of the zero energy for  $H_{1D}$  are

$$\psi_{\pm}(x, k_y, k_z) = \frac{1}{2\pi}\chi_{\pm}\sqrt{\lambda_3(k_y, k_z)}\exp(-\lambda_3(k_y, k_z)|x| + ik_y y + ik_z z) \quad (12)$$

with  $\lambda_3(k_y, k_z) = \frac{\hbar v}{2|b_0|} + \sqrt{\left(\frac{\hbar v}{2b_0}\right)^2 + k_y^2 + k_z^2}$  and  $\chi_+ = \frac{1}{2}(1, -\text{sgn}(b_0), i, -i\text{sgn}(b_0))^T$ ,  $\chi_- = \frac{1}{2}(1, \text{sgn}(b_0), -i, i\text{sgn}(b_0))^T$ . Using the two states as the basis, we obtain the effective Hamiltonian for the bound states at the interface,

$$H_{eff}(k_y, k_z) = \text{sgn}(b_0)(k_x\sigma_1 - k_y\sigma_2), \quad (13)$$

which describes a gapless Dirac cone located at the interface of the domain wall.

**Symmetry enforced band crossing** Generally, the symmetry-enforced band crossings can be movable at some high symmetry line [3, 4, 5, 6, 7, 8, 9, 10, 11] or pinned at a particular high-symmetry point in the Brillouin zone [12, 13, 14, 15, 16].

In 1D, the fermion doubling problem can be evaded by considering the nonsymmorphic symmetry which is a combination of a fractional lattice translation and a spatial operation. In this situation, the degenerate point is movable according to the model parameters. Consider a one-dimensional bipartite chain where the

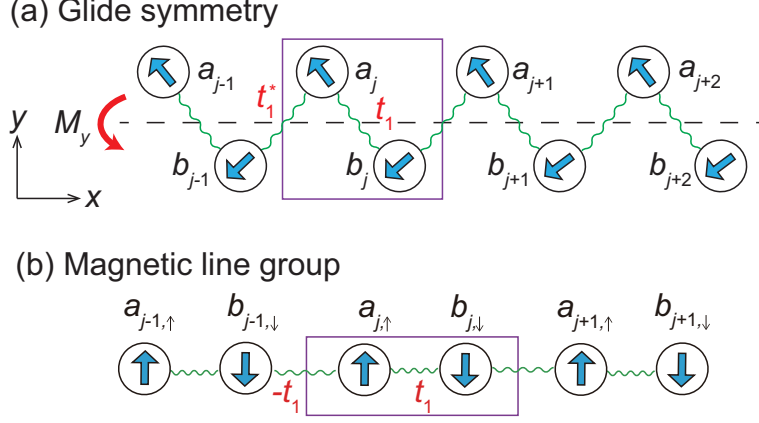


Figure 1: Illustration of (a) the glide symmetry and (b) the magnetic line group in one dimensional lattice.

two sites can be equivalently represented by a local up or down vector object as shown in Fig. 1(a). Under a transformation  $\bar{M}_y = M_y \mathbf{t}_{1/2}$  that is a combination of the mirror operator  $M_y$  and a spatial translation of half of the lattice spacing  $\mathbf{t}_{1/2}$ , the system is invariant.  $\bar{M}_y$  transforms the annihilation operators for the two sublattices as  $\bar{M}_y a_j \bar{M}_y^{-1} = b_j$  and  $\bar{M}_y b_j \bar{M}_y^{-1} = a_{j+1}$ , where  $a_j$  and  $b_j$  are the annihilation operators for the sublattices  $A$  and  $B$  in site  $j$ , respectively. A tight-binding model can be constructed as

$$H = \sum_j \left( t_1 a_j^\dagger b_j + t_2 a_j^\dagger b_{j-1} + \text{H.c.} \right), \quad (14)$$

where H.c. denotes the Hermitian conjugation,  $t_1$  and  $t_2$  are the intracell and intercell hopping strength, respectively. The glide mirror symmetry of  $H$  (i.e.,  $\bar{M}_y H \bar{M}_y^{-1} = H$ ) requires  $t_1 = t_2^*$ . In the basis of  $\psi_k = [a_k, b_k]^T$ , the Hamiltonian can be represented as

$$H = \sum_k \psi_k^\dagger \mathcal{H}_k \psi_k = \sum_k \psi_k^\dagger \begin{bmatrix} 0 & t_1 + t_1^* e^{ik} \\ t_1^* + t_1 e^{-ik} & 0 \end{bmatrix} \psi_k, \quad (15)$$

and the glide mirror operator is explicitly expressed as

$$\bar{M}_y = \begin{bmatrix} 0 & 1 \\ e^{-ik} & 0 \end{bmatrix}, \quad (16)$$

which is a function of  $k$ , a necessary condition for glide symmetry. As  $\bar{M}_y^2 = M_y^2 \mathbf{t}_{1/2}^2 = e^{-ik}$  is a translation for one unit cell, and  $[\bar{M}_y, \mathcal{H}_k] = 0$  thus the energy eigenstates can be labeled by the eigenvalues of  $\bar{M}_y$  which are  $\pm e^{-ik/2}$ . Upon shifting one reciprocal lattice vector  $G$ ,  $k \rightarrow k + G$ , the eigenvalues of  $\bar{M}_y$  switch places  $\pm e^{-i(k+G)/2} = \mp e^{-ik/2}$ , which requires that the two energy branches must have odd times of crossing in one Brillouin zone. The bulk spectrum for this model can be obtained as  $E_k = \pm \sqrt{2|t_1|^2 + t_1^{*2} e^{ik} + t_1^2 e^{-ik}}$  and there is a single band crossing point at  $k_c = \pi + \text{Im} \ln(t_1/t_1^*)$ . The low energy Hamiltonian  $H_{eff}$  can be obtained by expanding the full Hamiltonian (15) around the degenerate point. To the linear order  $\delta k$ , we have  $H_{eff} = v_f \begin{pmatrix} 0 & e^{ik_c/2} \\ e^{-ik_c/2} & 0 \end{pmatrix} \delta k$  with  $v_f = \text{Im}(t_1 e^{-ik_c/2})$ . There exists a unitary matrix  $\mathcal{C} = \begin{pmatrix} 0 & e^{ik_c/2} \\ e^{-ik_c/2} & 0 \end{pmatrix}$  commuting with  $H_{eff}$  which defines the chiral symmetry of the system in low energy limit. From Eq. (15), the off-diagonal element for  $Q$  matrix is  $q(k) = \frac{t_1 + t_1^* e^{ik}}{|t_1 + t_1^* e^{ik}|}$ . The winding number density  $iq^{-1}(k) \partial_k q(k) = -\frac{1}{2}$  is a constant for this special case which yields  $w_{1D} = -\frac{1}{2}$ .

The quantum anomalous semimetal in 1D can be also stabilized by the type-IV magnetic double line group generated by  $\bar{\mathcal{T}} = \{\mathcal{T} | \frac{1}{2}\}$  which is composed by the time reversal symmetry  $\mathcal{T}$  and a fractional lattice translation [16]. The fermion doubling problem is evaded since this time-reversal like symmetry is

represented different at  $k = 0$  and  $G/2$ . The degenerate point is pinned at  $k = G/2$  where has a 2D irreducible representation. The simplest example of symmetry  $\bar{T}$  is a two-sublattice-site antiferromagnet as shown in Fig. 1(b), where the spins on sites  $A$  are the time reverses of the spins on the sites  $B$ . To construct a model with symmetry  $\bar{T}$ , we consider the system with two sublattice sites of  $s$ -orbitals. At each lattice site, there are two spins. We have a total four bands model. The antiferromagnetic potential is assumed to be much stronger than other hopping and energy terms, the system is then effectively split into two two-bands systems.  $\bar{T}$  transforms the annihilation operators of the energetically identical two states as  $\bar{T}a_{j\uparrow}\bar{T}^{-1} = b_{j\downarrow}$  and  $\bar{T}b_{j\downarrow}\bar{T}^{-1} = -a_{j+1,\uparrow}$  where  $a_{j\uparrow}$  and  $b_{j\downarrow}$  are the annihilation operators for spin-up at the sublattices  $A$  or spin-down state at the sublattice  $B$  in site  $j$ . A tight-binding Hamiltonian for this two-band model can be constructed straightforwardly,

$$H = \sum_j \left( t_1 a_{j\uparrow}^\dagger b_{j\downarrow} + t_2 a_{j\uparrow}^\dagger b_{j-1\downarrow} + \text{H.c.} \right) \quad (17)$$

where  $t_1$  and  $t_2$  are the intracell and intercell hopping strength, respectively. The time-reversal like symmetry of  $H$ , i.e.,  $\bar{T}H\bar{T}^{-1} = H$ , enforces  $t_1 = -t_2$  for the hopping strength. We then construct a basis of  $\{a_{k\uparrow}, b_{k\downarrow}\}$  by the Fourier transformation  $a_{k\uparrow} = \frac{1}{\sqrt{N}} \sum_j e^{-ikR_j} a_{j\uparrow}$  and  $b_{k\downarrow} = \frac{1}{\sqrt{N}} \sum_j e^{-ikR_j} b_{j\downarrow}$  where  $N$  is the number of unit cells. We have chosen the periodic gauge condition  $a_{k+G,\uparrow} = a_{k\uparrow}$  and  $b_{k+G,\downarrow} = b_{k\downarrow}$ . In the basis  $\psi_k = [a_{k\uparrow}, b_{k\downarrow}]^T$ , the Hamiltonian is represented as  $H = \sum_k \psi_k^\dagger \mathcal{H}_k \psi_k$ . In terms of the Pauli matrices  $\sigma$  acting on the sublattice space,  $\mathcal{H}_k$  can be expressed as

$$\mathcal{H}_k = [\text{Re}t_1(1 - \cos k) + \text{Im}t_1 \sin k]\sigma_x + [\text{Re}t_1 \sin k - \text{Im}t_1(1 - \cos k)]\sigma_y. \quad (18)$$

After a basis transformation  $\frac{\text{Re}t_1}{|t_1|}\sigma_x - \frac{\text{Im}t_1}{|t_1|}\sigma_y \rightarrow \sigma'_x$  and  $\frac{\text{Im}t_1}{|t_1|}\sigma_x + \frac{\text{Re}t_1}{|t_1|}\sigma_y \rightarrow \sigma'_y$ , the Hamiltonian can be rewritten as  $\mathcal{H}_k = |t_1|(\sin k\sigma_y + 2\sin^2 \frac{k}{2}\sigma_x)$ . The band structure features an unpaired twofold Dirac fermion with the Wilson fermion in Eq. (1) in the main text.

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